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ORNEY DOCKET NO.	ATT	FIRST NAMED INVENTOR	FILING DATE	APPLICATION NO.
MINER	EXA			-
PAPER NUMBER	ART UNIT			
1				
	DATE MAILED:			

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

Office Action Summary

Application No.

Applicant(s)

08/866,129

Uemura et al.

Examiner

Douglas Wille

Group Art Unit 2814



X Responsive to communication(s) filed on <u>Sep</u>	o 27, 1999
This action is FINAL .	
Since this application is in condition for allow in accordance with the practice under Ex pair	vance except for formal matters, prosecution as to the merits is closed recorded or terms of the merits is closed and a second of the merits is closed or terms of the merits is closed or the merits in the merits is closed or the merits or the merits is closed or the merits or the merits in the merits is closed or the merits of the merits or the merits or the merits of the merits or the merits of the merits or the merits of the mer
s longer, from the mailing date of this commun	is action is set to expire 3 month(s), or thirty days, whichever ication. Failure to respond within the period for response will cause the § 133). Extensions of time may be obtained under the provisions of
Disposition of Claims	
X Claim(s) 1, 2, 4-14, 20, and 21	is/are pending in the application.
Of the above, claim(s)	is/are withdrawn from consideration.
	is/are allowed.
	is/are rejected.
	is/are objected to.
	are subject to restriction or election requirement.
The specification is objected to by the Ex The oath or declaration is objected to by Priority under 35 U.S.C. § 119 Acknowledgement is made of a claim for All Some* None of the CEF received. received in Application No. (Series received in this national stage appli	is/are objected to by the Examiner. a pproved disapproved. aminer.
*Certified copies not received:	0511000514001
Acknowledgement is made of a claim for	domestic priority under 35 U.S.C. § 119(e).
Attachment(s)	
Notice of References Cited, PTO-892 Information Disclosure Statement(s), PTC)-1449. Paper No(s).
Interview Summary, PTO-413	
	D
Notice of Draftsperson's Patent Drawing	Review, PTO-948

--- SEE OFFICE ACTION ON THE FOLLOWING PAGES ---

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DETAILED ACTION

Claim Rejections - 35 USC § 102

- 1. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
- 2. Claims 12 14 and 21 are rejected under 35 U.S.C. 102(e) as being anticipated by Nakamura et al.(*422)
- 3. With respect to claims 12 14, Nakamura et al.('422) show a group III compound semiconductor device (see Figure 1) with a p-type upper layer 13 and an electrode consisting of a layer of Ni with a layer of Au on top (column 5, line 49). Figure 7 shows a modification of the Figure 1 device which has a contact layer 15 and a bonding pad 17 that covers part of layer 15 and has a protective film of silicon oxide (column 10, line 26). The other properties in claim 12 are inherent in the materials.
- 4. With respect to claim 21, Nakamura ('422) shows a structure with a AuNi layer covering part of a Ni and Au layer and will inherently have the same properties as claimed.

Claim Rejections - 35 USC § 103

5. Claims 1, 2, 4 - 11, and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nakamura et al. (*422) in view of Manabe et al. and Nakamura et al. (*350).

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- Nakamura et al. (*422) show a group III compound semiconductor device (see Figure 1) 6. with a p-type upper layer 13 and an electrode consisting of a layer of Ni with a layer of Au on top (column 5, line 49). Figure 7 shows a modification of the Figure 1 device which has a contact layer 15 and a bonding pad 17 that covers part of layer 15 and has a protective film of silicon oxide (column 10, line 26). Nakamura et al. (422) show that the electrode layers are transparent (column 6, line 31). Nakamura et al. (422) also show that the bonding pad 17 is composed of Ni and Au but teach against the use of Al (in a two layer structure) since it can migrate to the electrode and can degrade it. Manabe et al. show the use of Al in a multilayer electrode stack (see Figure 6 and column 5, line 38) which has improved operating characteristics. It would have been obvious to modify the Nakamura et al.('422)device to include the Al layer as taught by Manabe et al. with the expectation that the two intervening layers will protect the electrode from deterioration. Nakamura et al. ('422) also teach annealing at 600 degrees (column 7, line 38) and teach the LED compound is In_xAl_xGa_{1-x-x}N. Nakamura et al. (*350) show that the silicon oxide protective layer is SiO₂ (column 34, line 66). The remainder of the claimed features are inherent in the choice of materials. Forming the layers in the sequence Ni-Au-Al follows the decreasing sequence of work functions and would also be obvious.
- 7. With respect to claim 20, Nakamura ('422) shows a structure with a AuNi layer covering part of a Ni and Au layer and will inherently have the same properties as claimed.

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Conclusions

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Douglas A. Wille whose telephone number is (703) 308-4949.

9. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose number is (703) 308-0956.

Olik Chaudhuri Supervisory Patent Examiner Art Unit 2814

DAW & Sec

October 27, 1999